

AC/DC Drivers

PWM type DC/DC converter IC Included 650V MOSFET

BM2PXX2 Series

General

The PWM type DC/DC converter (BM2PXX2) for AC/DC provide an optimum system for all products that include an electrical outlet.

BM2PXX2 supports both isolated and non-isolated devices, enabling simpler design of various types of low-power electrical converters.

BM2PXX2 built in a HV starter circuit that tolerates 650V, it contributes to low-power consumption.

With current detection resistors as external devices, a higher degree of design freedom is achieved. Since current mode control is utilized, current is restricted in each cycle and excellent performance is demonstrated in bandwidth and transient response.

The switching frequency is 65 kHz. At light load, the switching frequency is reduced and high efficiency is achieved.

A frequency hopping function is also on chip, which contributes to low EMI.

We can design easily, because $\mathsf{BM2PXX2}$ includes the switching MOSFET.

Basic specifications

- ■Operating Power Supply Voltage Range: VCC 8.9V to 26.0V DRAIN : ~650V
- Operating Current: Normal Mode

	BM2P012 :0.950mA (Typ.)
	BM2P032 :0.775mA(Typ)
	BM2P052 : 0.60mA(Typ)
	BM2P092 : 0.50mA(Typ)
	Burst Mode: 0.40mA(Typ.)
Oscillation Frequence	cy: 65kHz(Typ.)
Operating Temperating	ure: - 40deg. to +105deg.
■MOSFET ON Resist	

BM2P012:1.4Ω(Typ)

BM2P032:2.4Ω(Typ) BM2P052:4.0Ω(Typ) BM2P092:8.5Ω(Typ)

Application circuit

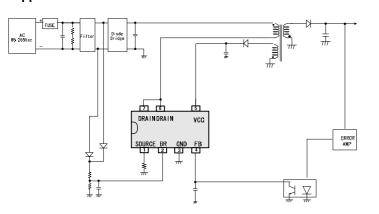


Figure 1. Application circuit

•Features

- PWM frequency : 65kHz
- PWM current mode method
- Burst operation when load is light
- Frequency reduction function
- Built-in 650V start circuit
- Built-in 650V switching MOSFET
- VCC pin under voltage protection
- VCC pin overvoltage protection
- SOURCE pin Open protection
- SOURCE pin Short protection
- SOURCE pin Leading-Edge-Blanking function
- Per-cycle over current protection circuit
- Soft start
- Secondary Over current protection circuit
- BR pin AC input low voltage protection
- BR pin AC input high voltage protection

Package

DIP7

9.20mm×6.35mm×4.30mm pitch 2.54mm (Typ.) (Typ.) (Typ.) (TYP.)



Applications

AC adapters and household appliances (vacuum cleaners, humidifiers, air cleaners, air conditioners, IH cooking heaters, rice cookers, etc.)

Line Up

Product	MOSFET ON resistor
BM2P012	1.4Ω
BM2P032	2.4Ω
BM2P052	4.0 Ω
BM2P092	8.5 Ω

OProduct structure : Silicon monolithic integrated circuit OThis product is not designed protection against radioactive rays

•Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Rating	Unit	Conditions
Maximum applied voltage 1	Vmax1	-0.3~30	V	VCC
Maximum applied voltage 2	Vmax2	-0.3~6.5	V	SOURCE, FB, BR
Maximum applied voltage 3	V	650	V	DRAIN
Drain current pulse	I _{DP}	10.40	А	P _w =10us, Duty cycle=1% (BM2P012)
Drain current pulse	I _{DP}	5.20	А	P _w =10us, Duty cycle=1% (BM2P032)
Drain current pulse	I _{DP}	2.60	А	P _w =10us, Duty cycle=1% (BM2P052)
Drain current pulse	I _{DP}	1.30	А	P _w =10us, Duty cycle=1% (BM2P092)
Allowable dissipation	Pd	2000	mW	When implemented
Operating temperature range	Topr	-40 ~ +105	°C	
Storage temperature range	Tstr	-55 ~ +150	°C	

(Note1) DIP7 : When mounted (on 74.2 mm × 74.2 mm, 1.6 mm thick, glass epoxy on double-layer substrate). Reduce to 16 mW/°C when Ta = 25° C or above.

•Operating Conditions(Ta=25°C)

Parameter	Symbol	Rating	Unit	Conditions
Power supply voltage range 1	VCC	8.9~26.0	V	VCC pin voltage
Power supply voltage range 2	V_{drain}	~650	V	DRAIN pin voltage

•Electrical Characteristics of MOSFET part (Unless otherwise noted, Ta = 25°C, VCC = 15 V)

Parameter	Symbol	Minimum	Specifications Standard	s Maximum	Unit	Conditions
[MOSFET Block]		Winningth	Standard	Maximum		
Between drain and source voltage	$V_{(\text{BR})\text{DDS}}$	650	-	-	V	$I_{D}=1mA / V_{GS}=0V$
Drain leak current	I _{DSS}	-	-	100	uA	V _{DS} =650V / V _{GS} =0V
On resistance	R _{DS(ON)}	-	1.4	2.0	Ω	I _D =0.25A / V _{GS} =10V (BM2P012)
On resistance	R _{DS(ON)}	-	2.4	3.6	Ω	I _D =0.25A / V _{GS} =10V (BM2P032)
On resistance	R _{DS(ON)}	-	4.0	5.5	Ω	I _D =0.25A / V _{GS} =10V (BM2P052)
On resistance	R _{DS(ON)}	-	8.5	12.0	Ω	I _D =0.25A / V _{GS} =10V (BM2P092)

•Electrical Characteristics (Unless otherwise noted, Ta = 25°C, VCC = 15 V) Specifications Unit Conditions Parameter Symbol Minimum Standard Maximum [Circuit current] BM2P012, FB=2.0V Circuit current (ON) 1 700 950 1200 μA I_{ON1} (at pulse operation) BM2P032, FB=2.0V Circuit current (ON) 1 775 1050 550 μA (at pulse operation) BM2P052, FB=2.0V 790 Circuit current (ON) 1 I_{ON1} 410 600 μΑ (at pulse operation) BM2P092, FB=2.0V Circuit current (ON) 1 350 500 650 μA I_{ON1} (at pulse operation) Circuit current (ON) 2 I_{ON2} 400 500 μA FB=0.0V(at burst operation) [VCC protection function] 12.50 VCC UVLO voltage 1 V_{UVLO1} 13.50 14.50 V VCC rise VCC drop VCC UVLO voltage 2 V_{UVLO2} 7.50 8.20 8.90 V VUVLO3= VUVLO1- VUVLO2 VCC UVLO hysteresis V_{UVLO3} 5.30 V VCC rise 26.0 27.5 29.0 V VCC OVP voltage 1 V_{OVP1} V_{OVP2} VCC OVP voltage 2 23.5 V VCC drop Latch released VCC voltage V_{UVLO2}-0.5 V VLATCH - V_{CHG1} VCC Recharge start voltage 7.70 8.70 9.70 V VCC Recharge stop voltage V_{CHG2} 12.00 13.00 14.00 V T_{LATCH} Latch mask time 50 100 150 us Thermal shut down temperature 145 T_{SD} 118 °C -[PWM type DCDC driver block] F_{SW1} Oscillation frequency 1 60 65 70 KHz FB=2.00V F_{SW2} Oscillation frequency 2 20 25 30 KHz FB=0.40V F_{DEL1} 4.0 Frequency hopping width 1 KHz FB=2.0V F_{CH} 175 Hopping fluctuation frequency 75 125 Hz Minimum pulse width T_{min} 400 ns -- T_{SS1} 0.70 0.30 0.50 Soft start time 1 ms $T_{\underline{SS2}}$ 1.00 Soft start time 2 0.60 1.40 ms T₅₅₃ Soft start time 3 1.20 2.00 2.80 ms T_{SS4} Soft start time 4 4.80 8.00 11.20 ms D_{max} 68.0 75.0 82.0 % Maximum duty FB pin pull-up resistance 30 37 kΩ R_{FB} 23 Gain 4.00 V/V Δ FB / Δ CS gain 0.500 FB burst voltage V_{BST} 0.300 0.400 V FB drop FB voltage of VDLT 1.100 1.250 1.400 V starting Frequency reduction mode 3.00 V FB OLP voltage 1a V_{FOLP1A} 2.60 2.80 Overload is detected (FB rise) FB OLP voltage 1b V_{FOLP1B} V 2.60 Overload is detected (FB drop) -FB OLP ON timer T_{FOLP1} 40 64 88 ms FB OLP Start up timer T_{FOLP1} 26 32 38 ms FB OLP OFF timer 358 512 666 T_{FOLP2} ms [Over current detection block] Overcurrent detection voltage V_{cs} 0.380 0.400 0.420 V Ton=0us Overcurrent detection voltage SS1 V_{CS_SS1} 0.100 V _ -0[ms] ~ Tss1[ms] Overcurrent detection voltage SS2 0.150 V TSS1 [ms] ~ TSS2 [ms] V_{CS_SS2} -_ V Overcurrent detection voltage SS3 V_{CS SS3} 0.200 _ TSS2 [ms] ~ TSS3[ms] _ Overcurrent detection voltage SS4 V V_{CS_SS4} _ 0.300 _ TSS3 [ms] ~ TSS4 [ms] Leading Edge Blanking Time 250 T_{LEB} -ns Over current detection AC Voltage **K**_{cs} 12 20 28 mV/us compensation factor SOURCE pin V_{CSSHT} 0.020 0.050 0.080 V short protection voltage [Start circuit block] Start current 1 START1 0.100 0.500 1.000 mĀ VCC= 0V Start current 2 VCC=10V 1.000 3.000 6.000 mΑ I_{STAR} Inflow current from Drain pin after UVLO released UVLO. OFF current 10 20 uA START3 When MOSFET is OFF

Start current switching voltage	V _{sc}	0.800	1.500	2.100	V	
[BR pin function]						
BR UVLO detection voltage1	V _{BR1}	0.40	0.50	0.60	V	BR ↑
BR UVLO voltage 2	V _{BR2}	-	0.35	-	V	BR ↓
BR UVLO hysteresis	V _{BR3}	-	0.15	-	V	V _{BR3} =V _{BR1} -V _{BR2}
BR UVLO detection delay time1	T _{BR1}	50	100	150	us	BR ↑
BR UVLO detection delay time2	T _{BR2}	150	256	350	ms	BR ↓
BR OVP detection voltage1	V _{BR4}	-	2.10	-	V	BR ↑
BR OVP detection valtage2	V _{BR5}	-	2.00	-	V	BR ↓
BR OVP hysteresis	V _{BR6}	-	0.10	-	V	V _{BR3} =V _{BR1} -V _{BR2}
BR OVP detection delay time1	T _{BR3}	50	100	150	us	BR ↑
BR OVP detection delay time2	T _{BR4}	50	100	150	us	BR ↓

•PIN DESCRIPTIONS

Table 1. Pin Description

NO.	Pin Name	1/0	Function	ESD Diode		
NO.	Pin Name	I/O	Function	VCC	GND	
1	SOURCE	I/O	MOSFET SOURCE pin	0	0	
2	BR	-	Input AC voltage monitor pin	-	0	
3	GND	I/O	GND pin	0	-	
4	FB		Feedback signal input pin	-	0	
5	VCC	Ι	Power supply input pin	-	0	
6	DRAIN	I/O	MOSFET DRAIN pin	-	-	
7	DRAIN	I/O	MOSFET DRAIN pin	-	-	

•I/O Equivalent Circuit Diagram

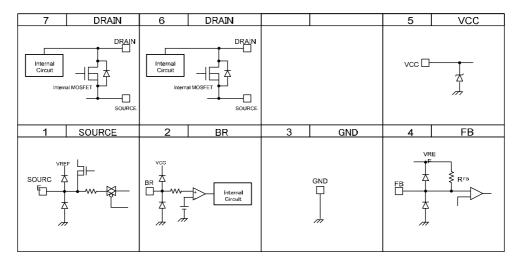


Figure 2. I/O Equivalent Circuit Diagram

Block Diagram

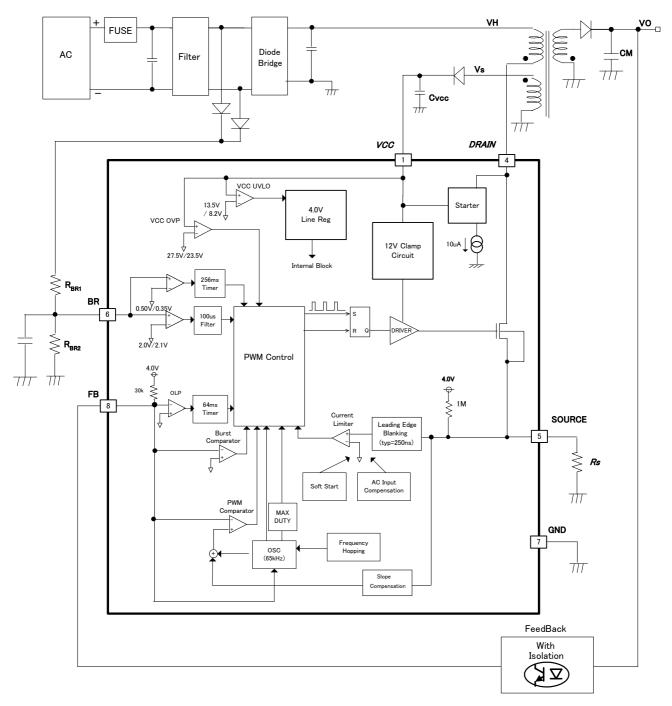


Figure 3. Block Diagram

Description of Blocks

(1) Start circuit (DRIAN : 6,7pin)

This IC built in Start circuit (tolerates 650V). It enables to be low standby mode electricity and high speed starting. After starting, consumption power is idling current I_{START3}(typ=10uA) only.

Reference values of Starting time are shown in Figure-6. When Cvcc=10uF it can start less than 0.1 sec.

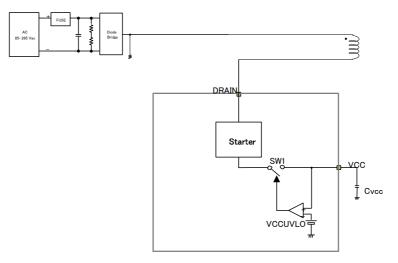
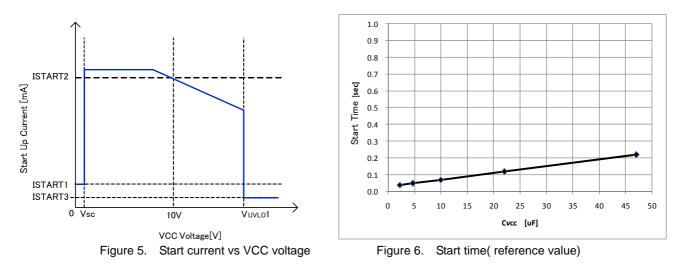


Figure 4. Block diagram of start circuit



* Start current flows from the DRAIN pin

- ex) Consumption power of start circuit only when the Vac=100V PVH=100V* $\sqrt{2}$ *10uA=1.41mW
- ex) Consumption power of start circuit only when the Vac=240V PVH=240V* $\sqrt{2}$ *10uA=3.38mW

(2) Start sequences (Soft start operation, light load operation, and auto recovery operation during overload protection)

Start sequences are shown in Figure 7. See the sections below for detailed descriptions.

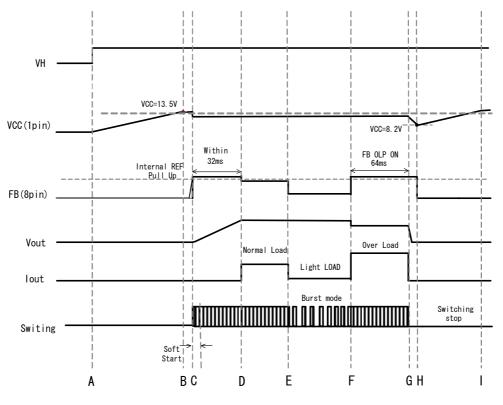


Figure 7. Start sequences Timing Chart

A : Input voltage VH is applied

B : This IC starts operating VCC pin voltage rises when VCC > V_{UVLO1} (13.5 V typ).
 Switching function starts when other protection functions are judged as normal.
 Between the secondary output voltage become constant level, because the VCC pin consumption current causes the VCC value to drop. VCC recharge function start if VCC voltage < V_{CHG1} (8.7V typ)

C : With the soft start function, overcurrent limit value is restricted to prevent any excessive rise in voltage or current. D : When the switching operation starts, VOUT rises.

The output voltage become to stable state, also VCC voltage become to stable state through auxiliary winding. Please set to achieve at the rated voltage within the T_{FOLP1b} period (32ms typ) from VCC voltage > V_{UVLO1} .

E : When there is a light load it reaches FB voltage < V_{Bst} (= 0.4Vtyp, burst operation is used to keep power consumption down.

During burst operation, it becomes low-power consumption mode.

F : When the FB Voltage> V_{FOLP1A} (=2.8V.typ), it becomes a overload

G: When FB pin voltage keeps V_{FOLP1A} (= 2.8V typ) at or above T_{FOLP} (64ms typ), the overload protection function is triggered and switching stops 64mS later. if the FB pin voltage becomes FB<V_{FOLP1B} even once, the IC's FB OLP timer is reset.
 H : If the VCC voltage drops to VCC < V_{UVL02} (7.7Vtyp) or below, restart is executed.

I : The IC's circuit current is reduced and the VCC pin value rises. (Same as B)

(3) VCC pin protection function

BM2PXX2 built in VCC low voltage protection function of VCCUVLO (Under Voltage Lock Out), over voltage protection function of VCC OVP (Over Voltage Protection) and VCC charge function that operates in case of dropping the VCC voltage.

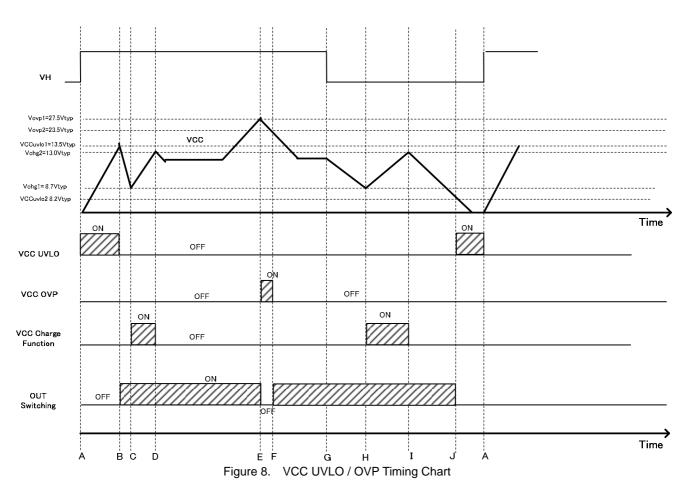
This function monitors VCC pin and prevent VCC pin from destroying switching MOSFET at abnormal voltage.

VCC charge function stabilizes the secondary output voltage to be charged from the high voltage line by start circuit at dropping the VCC voltage.

(3-1) VCC UVLO 🗡 VCC OVP function

VCCUVLO is auto recovery protection. VCCOVP is auto recovery protection that has voltage hysteresis. Refer to the operation figure-8.

Swiching is stopped by the VCCOVP function when VCC pin voltage > Vovp1(typ=27.5V), and Swiching is restart when VCC pin voltage < Vovp2(typ=23.5V)



A:DRAIN voltage input, VCC pin voltage starts rising.

B:VCC>Vuvlo1, DC/DC operation starts

C:VCC< V_{CHG1}, VCC charge function operates and the VCC voltage is rise.

D:VCC > V_{CHG2} , VCC charge function is stopped.

 $E:VCC > V_{OVP1}$ continues T_{LATCH} (typ =100us), switching is stopped by the VCCOVP function.

F:VCC < V_{OVP2}, Swiching operation restarts

G:VH is OPEN.VCC Voltage is fall.

H:Same as C.

I:Same as D.

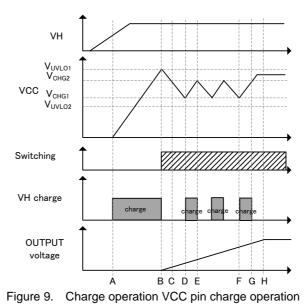
J: VCC<VuvIo2, Swiching is stoped by the VCC UVLO function

(3-2) VCC Charge function

VCC charge function operates once the VCC pin >V_{UVL01} and the DC/DC operation starts then the VCC pin voltage drops to $<V_{CHG1}$. At that time the VCC pin is charged from DRAIN pin through start circuit.

By this operation, BM2PXX2 doesn't occur to start failure.

VCC pin voltage is rise, then VCC >V_{CHG2}, charge is stopped. The operations are shown in figure-9.



A:DRAIN pin voltage rises, charge starts to VCC pin by the VCC charge function.

 $B:VCC > V_{UVLO1}, VCC UVLO function releases, VCC charge function stops, DC/DC operation starts. C:When DC/DC operation starts, the VCC voltage drops.$

D:VCC $< V_{CHG1}$, VCC recharge function operates.

 $E:VCC > V_{CHG1}$, VCC recharge function operations to be a set of the set

 $F:VCC < V_{CHG1}, VCC$ recharge function stops.

 $G:VCC < V_{CHG1}, VCC$ recharge function operates $G:VCC < V_{CHG1}, VCC$ recharge function stops.

H:After start of output voltage finished, VCC is charged by the auxiliary winding VCC pin stabilizes.

(4) DCDC driver (PWM comparator, frequency hopping, slope compensation, OSC, burst)

BM2PXX2 is current mode PWM control.

An internal oscillator sets a fixed switching frequency (65kHz typ).

BM2PXX2 is integrated switching frequency hopping function which changes the switching frequency to fluctuate as shown in figure-10 below.

The fluctuation cycle is 125 Hz typ.

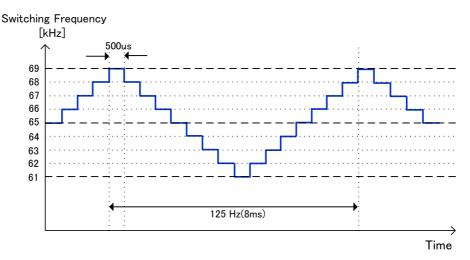


Figure 10. Frequency hopping function

Max duty cycle is fixed as 75% (typ) and MIN pulse width is fixed as 400 ns (typ).

With current mode control, when the duty cycle exceeds 50% sub harmonic oscillation may occur.

As a countermeasure to this, BM2PXX2 is built in slope compensation circuits.

BM2PXX2 is built in burst mode circuit and frequency reduction circuit to achieve lower power consumption, when the load is light.

FB pin is pull up by R_{FB} (30 k Ω typ).

FB pin voltage is changed by secondary output voltage (secondary load power).

FB pin is monitored, burst mode operation and frequency detection start.

Figure 11 shows the FB voltage, and switching frequency, DCDC operation

•mode1 : Burst operation

mode2: Frequency reduction operation.

mode3 : Fixed frequency operation.(operate at the max frequency)

·mode4 : Over load operation.(detect the over load state and stop the pulse operation)

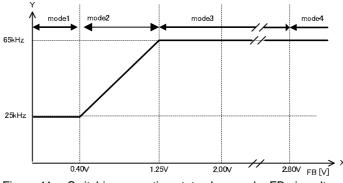


Figure 11. Switching operation state changes by FB pin voltage

(5) Over Current limiter

BM2PXX2 is built in Over Current limiter per cycle. If the SOURCE pin over a certain voltage, switching is stopped. It is also built in AC voltage compensation function. The function is rise over current limiter level by time to compensate at the max power for AC voltage change.

Shown in figure-12,13,14.

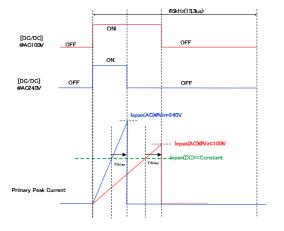


Figure 12. No AC voltage compensation function

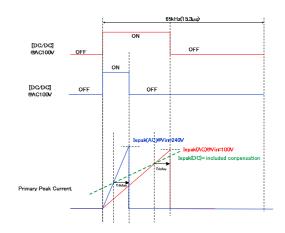
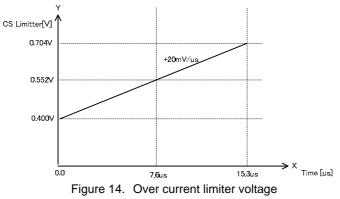


Figure13. buit-in AC compensation voltage

Primary peak current is decided as the formula below.

Primary peak current: Ipeak = Vcs/Rs + Vdc/Lp*Tdelay

 V_{cs} : Over current limiter voltage internal IC, Rs: Current detection resistance, V_{dc} input DC voltage, L_{p} : Primary inductance, T_{delay}: delay time after detection of over current limiter



(6) L.E.B period

When the driver MOSFET is turned ON, surge current occurs at each capacitor component and drive current. Therefore, when SOURCE pin voltage rises temporarily, the detection errors may occur in the over current limiter circuit. To prevent detection errors, DRAIN is switched from high to low and the SOURCE signal is masked for 250 ns by the on-chip LEB (Leading Edge Blanking) function.

(7) SOURCE pin (1pin) short protection function

When the SOURCE pin (1pin) is shorted, BM2PXX2 is over heat. BM2PXX2 built in short protection function to prevent destroying.

(8) SOURCE pin (1pin) open protection

If the SOURCE pin becomes OPEN, BM2PXX2 may be damaged. To prevent to be damaged, BM2PXX2 built in OPEN protection circuit (auto recovery protection).

(9) Output over load protection function (FB OLP Comparator)

The output overload protection function monitors the secondary output load status at the FB pin, and stops switching when an overload occurs. When there is an overload, the output voltage is reduced and current no longer flows to the photo coupler, so the FB pin voltage rises.

When the FB pin voltage > V_{FOLP1A} (2.8 V typ) continuously for the period T_{FOLP1} (64ms typ), it is judged as an overload and stops switching.

When the FB pin > V_{FOLP1A} (2.8 V typ), if the voltage goes lower than V_{FOLP1B} (2.6V typ) during the period T_{FOLP1} (64ms typ), the overload protection timer is reset. The switching operation is performed during this period T_{FOLP1} (64ms typ).

At startup, the FB voltage is pulled up to the IC's internal voltage, so operation starts at a voltage of V_{FOLP1A} (2.8 V typ) or above. Therefore, at startup the FB voltage must be set to go to V_{FOLP1B} (2.6 Vtyp) or below during the period T_{FOLP1} (64ms typ), and the secondary output voltage's start time must be set within the period T_{FOLP1} (64ms typ) following startup of the IC. Recovery from the once detection of FBOLP, after the period T_{FOLP2} (512 ms typ)

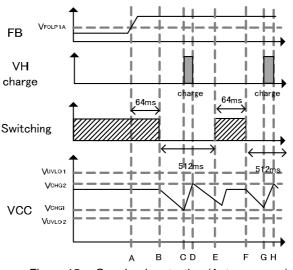


Figure 15. Over load protection (Auto recovery)

A: The FBOLP comparator detects over load for FB>V_{\mbox{FOLP1A}}

B: States of A continuously for the period T_{FOLP1} (64ms typ), it is judged as an overload and stops switching after 64ms later.
 C: While switching stops for the over load protection function, the VCC pin voltage drops and VCC pin voltage reaches < V_{CHG1}, the VCC charge function operates so the VCC pin voltage rises.

D: VCC charge function stops when VCC pin voltage > V_{CHG2}

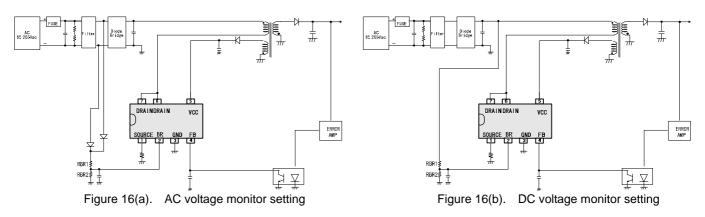
E: If T_{FOLP2} (typ =512ms) go on from B point, Switching function starts on soft start.

F: If T_{FOLP1b} (typ=64ms) go on from E point to continues a overload condition (FB>V_{FOLP1A}), Switching function stops at F point. G: While switching stops VCC pin voltage drops to < V_{CHG1} , VCC charge function operates and VCC pin voltage rises.

H: If VCC pin (1pin) voltage becomes over V_{CHG2} by the VCC charge function, VCC charge function operation stops.

(10) Input voltage protection function

This IC has BR-UVLO function and BR-OVP function to monitor input voltage. By monitoring input voltage, it can be prevented from breaking of IC. AC voltage and DC voltage can be monitored by BR pin.



BRUVLO function can protect the breaking of IC when input voltage is low.

•Operation mode of protection circuit

Operation mode of protection functions are shown in table2.

lable2 (Operation mode of protection circuit
Function	Operation mode
VCC Under Voltage Locked Out	Auto recovery
VCC Over Voltage Protection	Auto recovery
TSD	Latch (with 100us timer)
FB Over Limited Protection	Auto recovery(with 64ms timer)
SOURCE Short Protection	Auto recovery
SOURCE Open Protection	Auto recovery
BR UVLO	Auto recovery (with 256ms)
BR OVP	Auto recovery (with 100us timer)

Table2	Operation mode of protection circuit
Tablez	

•Sequence

The sequence diagram is show in Fig-17. All condition transits OFF Mode VCC<8.2V

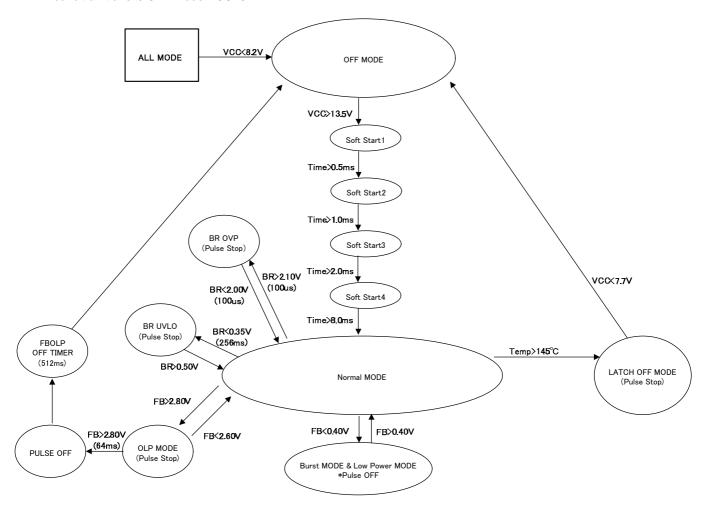


Figure 17. The sequence diagram

• Thermal loss

The thermal design should set operation for the following conditions. (Since the temperature shown below is the guaranteed temperature, be sure to take a margin into account.)

- 1. The ambient temperature Ta must be 105 $^\circ\!\text{C}$ or less.
- 2. The IC's loss must be within the allowable dissipation Pd.

The thermal abatement characteristics are as follows. (PCB: 74.2 mm × 74.2mm × 1.6 mm, mounted on glass epoxy double-layer substrate)

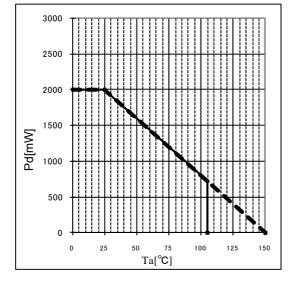
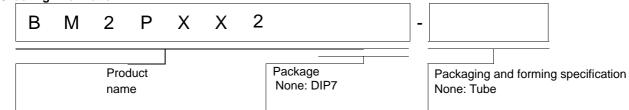


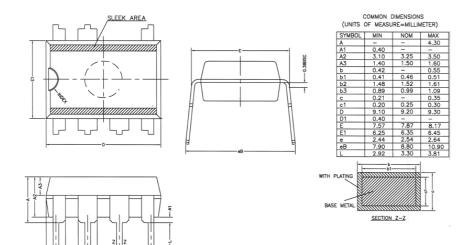
Figure 18. DIP7 Thermal Abatement Characteristics

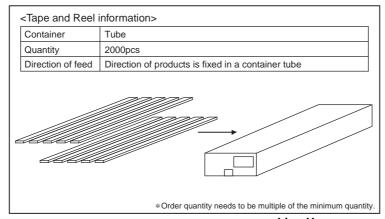
Ordering Information



• Physical Dimension Tape and Reel Information

DIP7

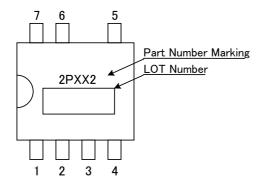




Making Diagram

●Line-Up

DIP7



+ (0.35

Product name (BM2PXX2)
BM2P012
BM2P032
BM2P052
BM2P092

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a 70mm x 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

Operational Notes – continued

11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

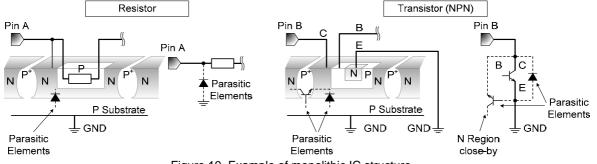


Figure 19. Example of monolithic IC structure

13. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

14. Area of Safe Operation (ASO)

Operate the IC such that the output voltage, output current, and power dissipation are all within the Area of Safe Operation (ASO).

15. Thermal Shutdown Circuit(TSD)

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. The IC should be powered down and turned ON again to resume normal operation because the TSD circuit keeps the outputs at the OFF state even if the TJ falls below the TSD threshold.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

16. Over Current Protection Circuit (OCP)

This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

date	Rev. No.	Revision Point
2012.07.19	001	New Release
2013.11.18	003	 P7 An explanation for Figure7 P8 An explanation for VCC_UVLO/VCC_OVP function An explanation for Figure8 P11 An explanation for Over Current limiter P12 An explanation for Output over load protection function An explanation for Figure15 P13 Figure16

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CLASSⅣ		CLASSⅢ	

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 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
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- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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QR code printed on ROHM Products label is for ROHM's internal use only.

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